ΡΛΝ	JIT
	SEMI
	CONDUCTOR



Current

#### Features

Voltage

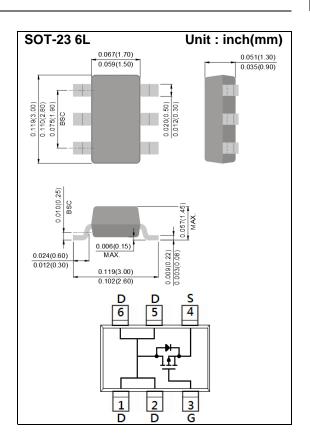
RDS(ON) , VGS@-4.5V, ID@-4.4A<82mΩ</li>

-20 V

- Rds(on) , Vgs@-2.5V, Id@-2.8A<110m $\Omega$
- RDS(ON) , VGS@-1.8V, ID@-1.5A<146mΩ
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

#### **Mechanical Data**

- Case: SOT-23 6L Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0005 ounces, 0.014 grams
- Marking: S13



### Maximum Ratings and Thermal Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

-4.4A

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V <sub>DS</sub>	-20	V
Gate-Source Voltage	V <sub>GS</sub>	<u>+</u> 12	V	
Continuous Drain Current		I <sub>D</sub>	-4.4	А
Pulsed Drain Current		lом	-17.6	А
Power Dissipation	T <sub>a</sub> =25⁰C	PD	2	W
	Derate above 25°C		16	mW/°C
Operating Junction and Storage Temperature Range		TJ,Tstg	-55~150	°C
Typical Thermal Resistance - Junction to Ambient <sup>(Note 3)</sup>		R <sub>θJA</sub>	62.5	°C/W



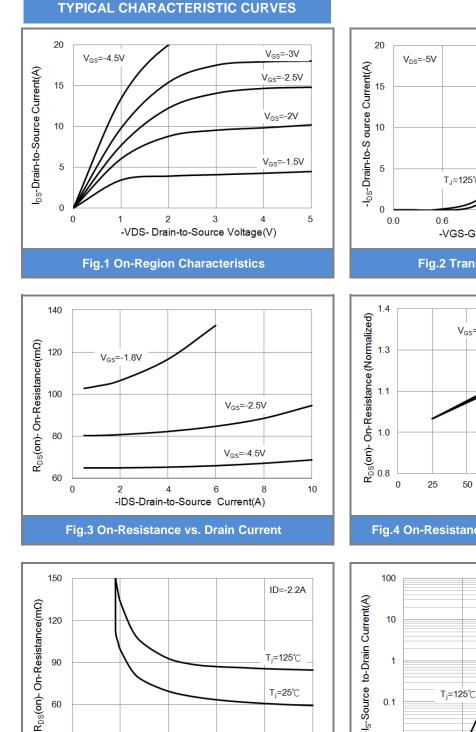
#### Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static		·				
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =-250uA	-20	-	-	V
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =-250uA	-0.4	-0.65	-1.2	V
Drain-Source On-State Resistance	RDS(on)	V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-4.4A	-	65	82	mΩ
		V <sub>GS</sub> =-2.5V, I <sub>D</sub> =-2.8A	-	82	110	
		V <sub>GS</sub> =-1.8V, I <sub>D</sub> =-1.5A	-	104	146	
Zero Gate Voltage Drain Current	IDSS	V <sub>DS</sub> =-20V, V <sub>GS</sub> =0V	-	0.01	-1	uA
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = <u>+</u> 12V, V <sub>DS</sub> =0V	-	<u>+</u> 10	<u>+</u> 100	nA
Dynamic						
Total Gate Charge	Qg	V <sub>DS</sub> =-10V, I <sub>D</sub> =-4.4A, V <sub>GS</sub> =-10V <sup>(Note 1,2)</sup>	-	7	-	nC
Gate-Source Charge	$Q_gs$		-	1.1	-	
Gate-Drain Charge	$Q_gd$		-	1.8	-	
Input Capacitance	Ciss	V <sub>DS</sub> =-10V, V <sub>GS</sub> =0V,	-	522	-	pF
Output Capacitance	Coss		-	55	-	
Reverse Transfer Capacitance	Crss	f=1.0MHZ	-	40	-	
Switching		·				
Turn-On Delay Time	td <sub>(on)</sub>		-	10	-	
Turn-On Rise Time	tr	V <sub>DD</sub> =-10V, I <sub>D</sub> =-4.4A, V <sub>GS</sub> =-10V,	-	4	-	ns
Turn-Off Delay Time	td <sub>(off)</sub>			35		
Turn-Off Fall Time	tf	$R_G=6\Omega^{(Note 1,2)}$	-	5	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	ls		-	-	-2.0	А
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =-1.0A, V <sub>GS</sub> =0V	-	0.75	-1.2	V

NOTES :

- 1. Pulse width</br>
- 2. Essentially independent of operating temperature typical characteristics.
- 3. ReJA is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper
- 4. The maximum current rating is package limited



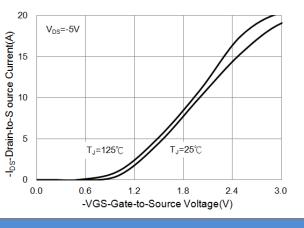


T<sub>j</sub>=25℃

10

2 4 6 8 -VGS-Gate-to-Source Voltage(V)

Fig.5 On-Resistance Variation with VGS.





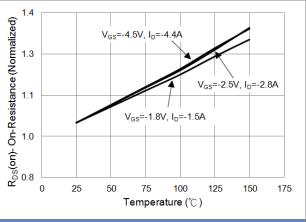
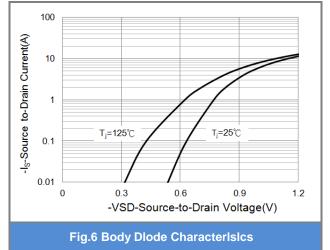


Fig.4 On-Resistance vs. Junction temperature

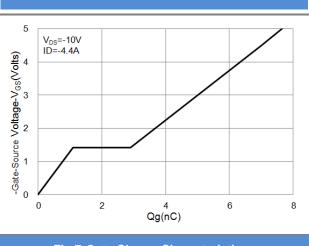


60

30

0





**TYPICAL CHARACTERISTIC CURVES** 

Fig.7 Gate-Charge Characteristics

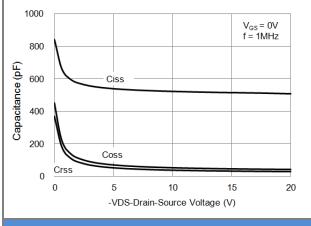


Fig.9 Capacitance vs. Drain-Source Voltage.

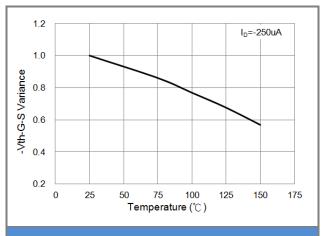


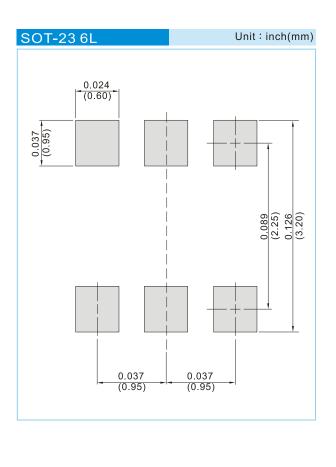
Fig.8 Threshold Voltage Variation with Temperature.



### PART NO. PACKING CODE VERSION

Part No. Packing Code	Package Type	Packing Type	Marking	Version
PJS6413_S1_00001	SOT-23 6L	3K pcs / 7" reel	S13	Halogen free RoHS compliant
PJS6413_S2_00001	SOT-23 6L	10K pcs / 13" reel	S13	Halogen free RoHS compliant

### MOUNTING PAD LAYOUT







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